

Features

- AEC-Q101 Qualified
- Trench Power LV MOSFET Technology
- Excellent Package For Heat Dissipation
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device ^(Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

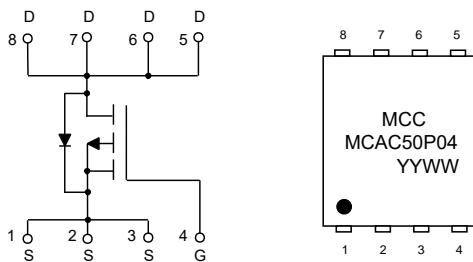
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 50°C/W Junction to Ambient^(Note2)
- Thermal Resistance: 1.3°C/W Junction to Case

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	-40	V
Gate-Source Voltage	V _{GS}	±20	V
Continuous Drain Current	I _D	-50	A
T _C =100°C	I _D	-31	
Pulsed Drain Current ^(Note3)	I _{DM}	-200	A
Total Power Dissipation ^(Note4)	P _D	96	W
Single Pulsed Avalanche Energy ^(Note5)	E _{AS}	200	mJ

Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of R_{θJA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-case thermal resistance.
5. V_{DD}=-30V, V_{GS}= -10V, L= 2mH

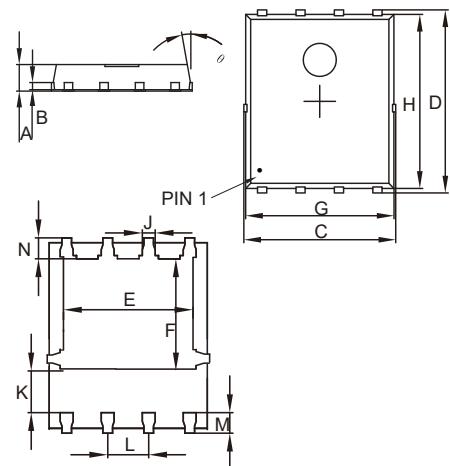
Internal Structure and Marking Code



4 codes in total
YY is the year
WW is the week

P-CHANNEL MOSFET

DFN5060



DIM	DIMENSIONS				NOTE	
	INCHES		MM			
	MIN	MAX	MIN	MAX		
A	0.031	0.047	0.80	1.20		
B	0.010		0.254		TYP.	
C	0.193	0.222	4.90	5.64		
D	0.232	0.250	5.90	6.35		
E	0.148	0.167	3.75	4.25		
F	0.126	0.154	3.20	3.92		
G	0.189	0.213	4.80	5.40		
H	0.222	0.239	5.65	6.06		
K	0.045	0.059	1.15	1.50		
J	0.012	0.020	0.30	0.50		
L	0.046	0.054	1.17	1.37		
M	0.012	0.028	0.30	0.71		
N	0.016	0.028	0.40	0.71		

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-40			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-40V, V_{GS}=0V$			-1	μA
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-1.0	-1.4	-2.5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=-10V, I_D=-20A$		10	13	$m\Omega$
		$V_{GS}=-4.5V, I_D=-10A$		13	20	
Gate Resistance	R_g	F=1 MHz, Open drain		9		Ω
Diode Characteristics						
Continuous Body Diode Current	I_S				-50	A
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=-20A$			-1.2	V
Reverse Recovery Time	t_{rr}	$I_F=-4A, dI_F/dt=100A/\mu s$		51		ns
Reverse Recovery Charge	Q_{rr}			41		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=-30V, V_{GS}=0V, f=1MHz$		3302		pF
Output Capacitance	C_{oss}			224		
Reverse Transfer Capacitance	C_{rss}			198		
Total Gate Charge	Q_g	$V_{DS}=-20V, V_{GS}=-10V, I_D=-4A$		75		nC
Gate-Source Charge	Q_{gs}			8		
Gate-Drain Charge	Q_{gd}			15		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=-20V, V_{GS}=-10V, R_{GEN}=3\Omega, I_{DS}=-4A$		7.5		ns
Turn-On Rise Time	t_r			4.2		
Turn-Off Delay Time	$t_{d(off)}$			200		
Turn-Off Fall Time	t_f			70		

Curve Characteristics

Fig. 1 - Typical Output Characteristics

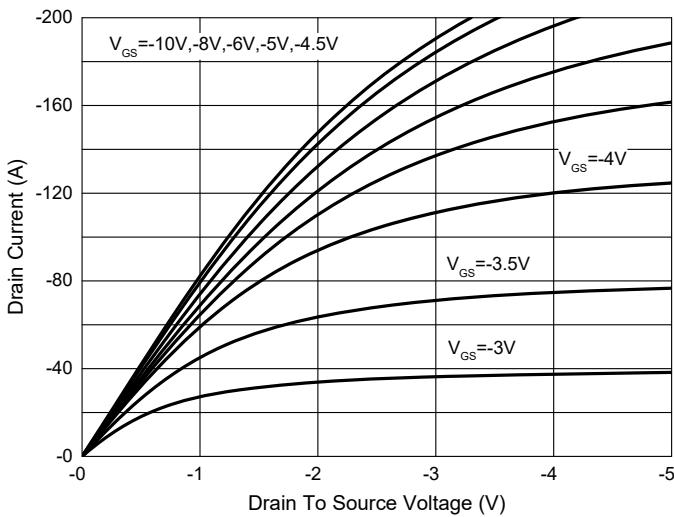


Fig. 2 - Transfer Characteristics

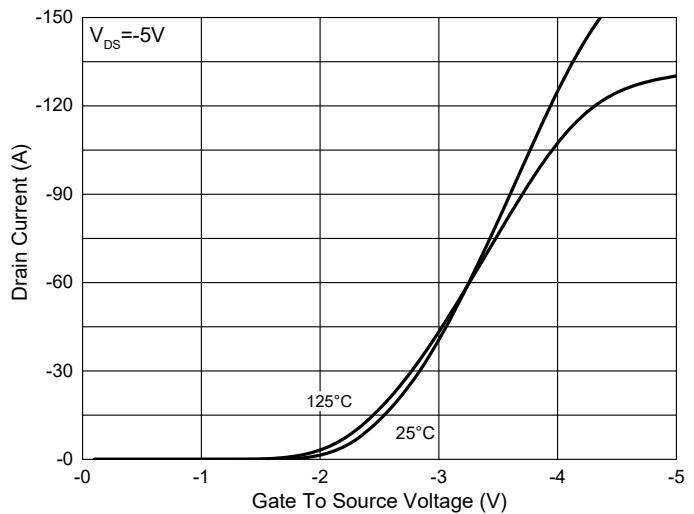


Fig. 3 - $R_{DS(ON)}$ — V_{GS}

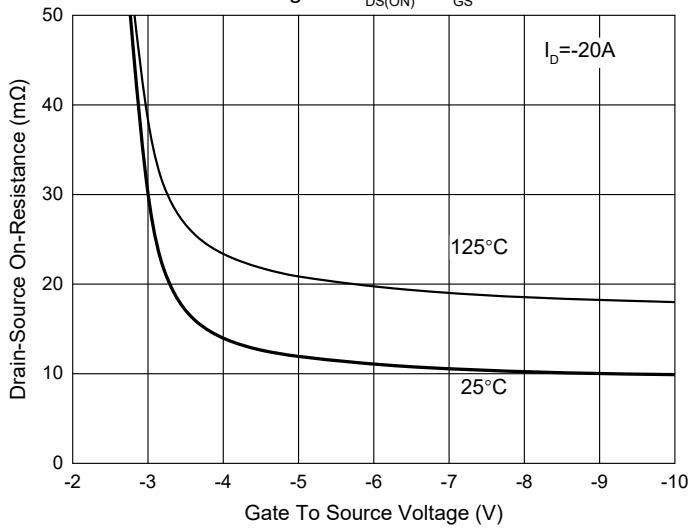


Fig. 4 - $R_{DS(ON)}$ — I_D

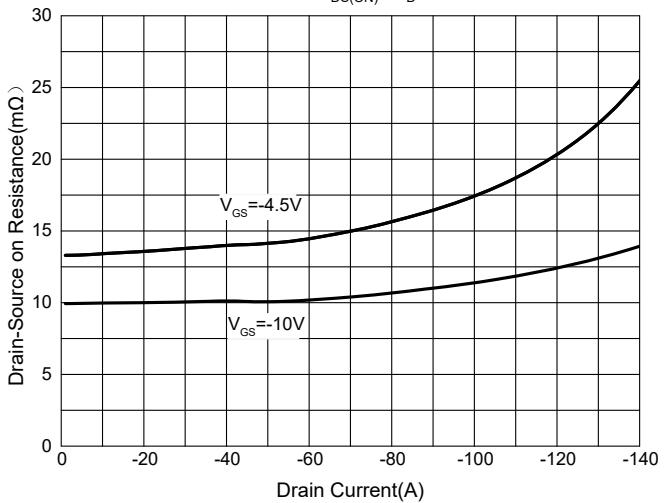


Fig. 5 - Capacitance Characteristics

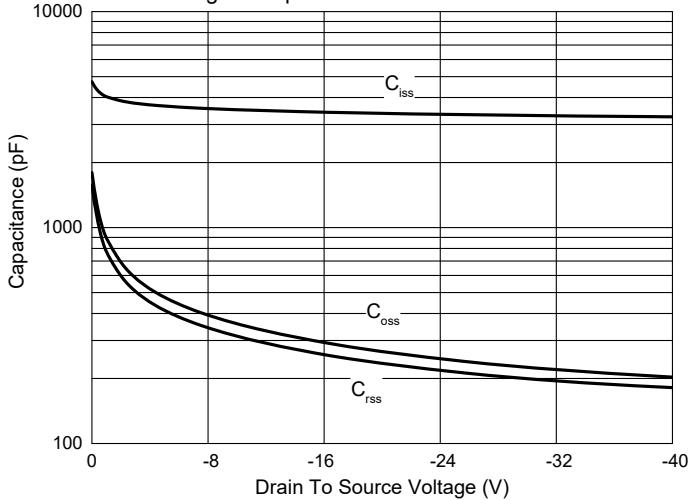
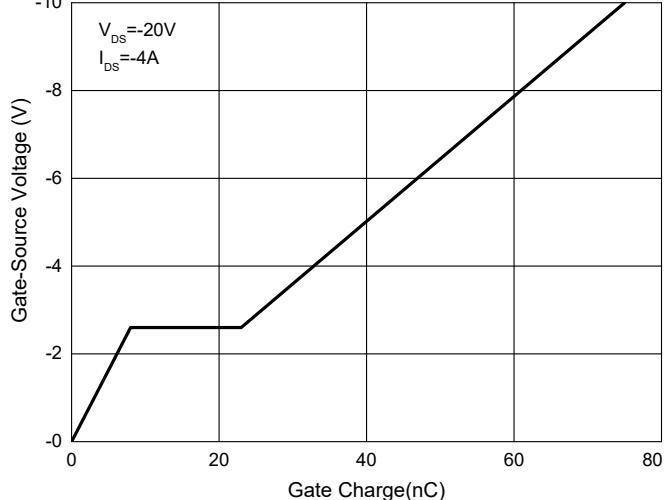
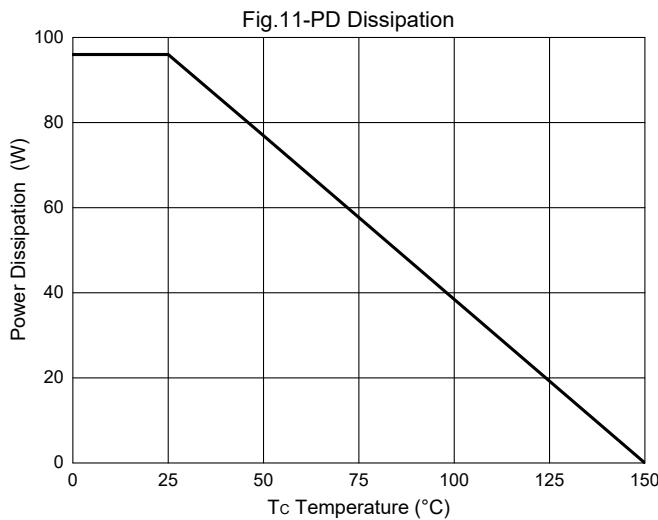
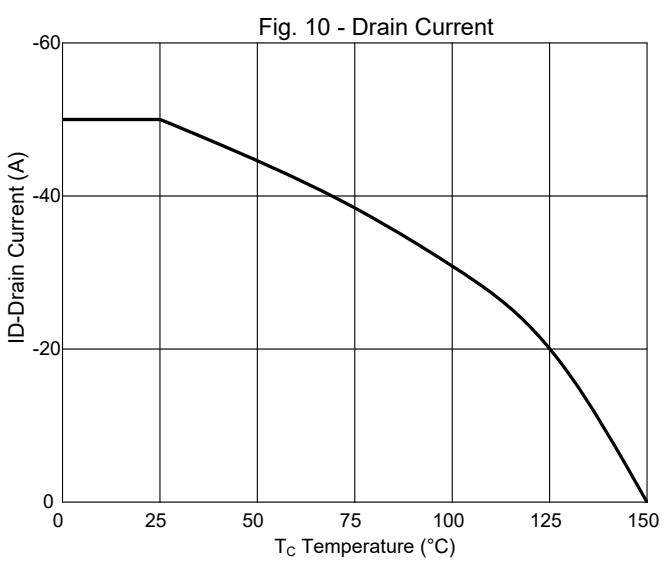
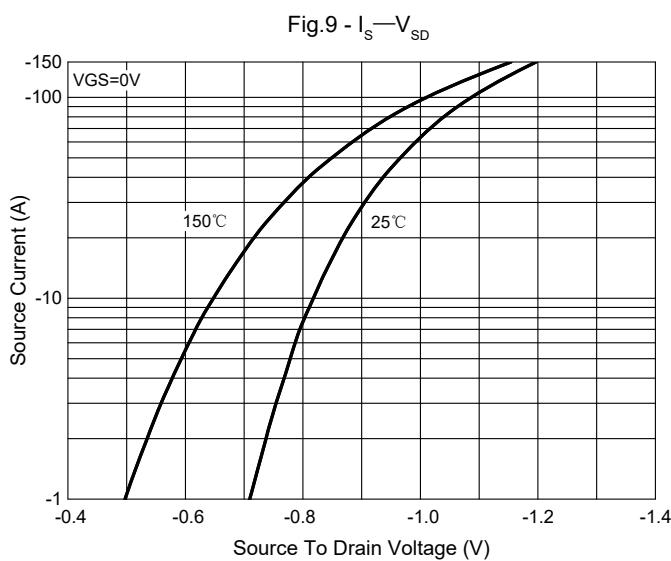
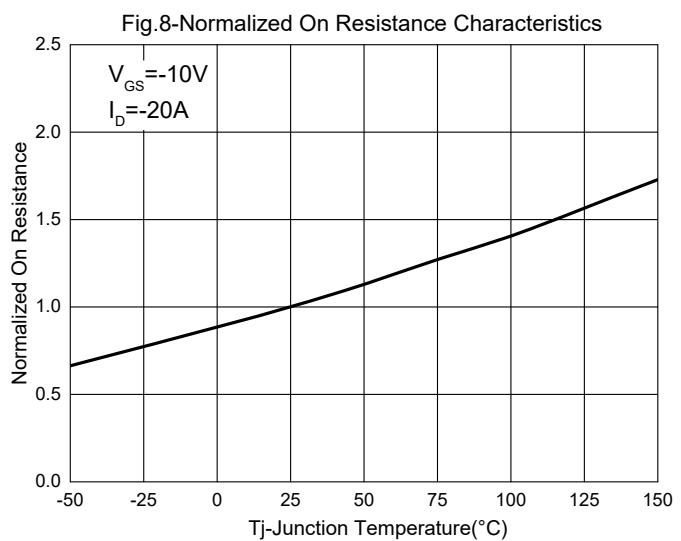
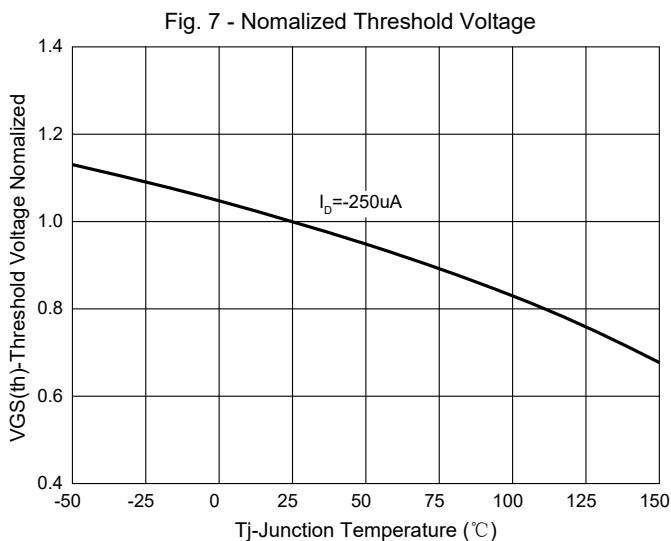


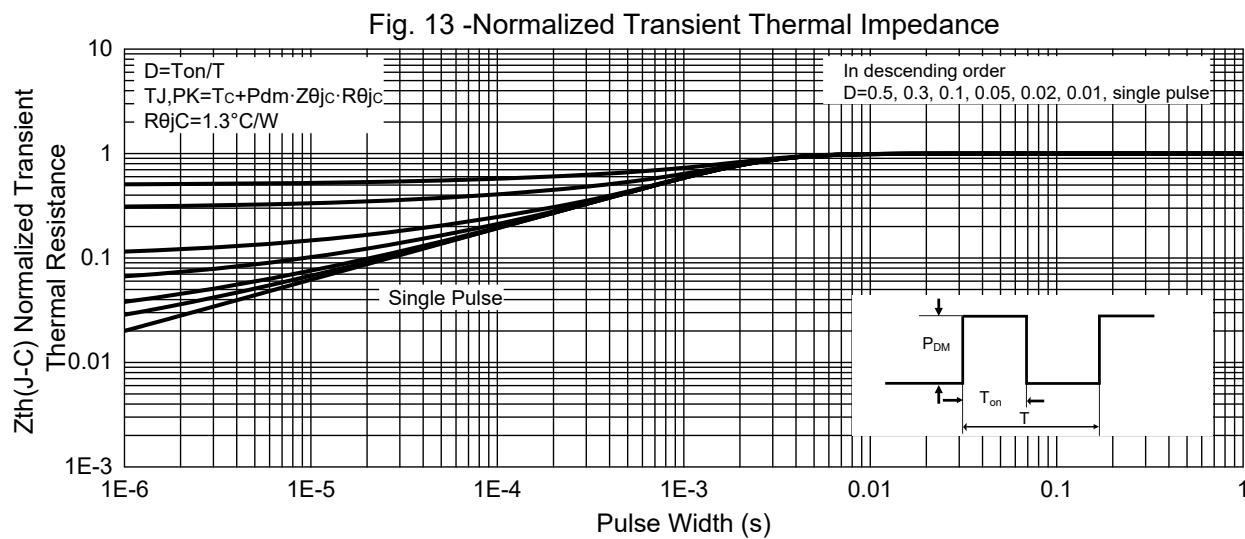
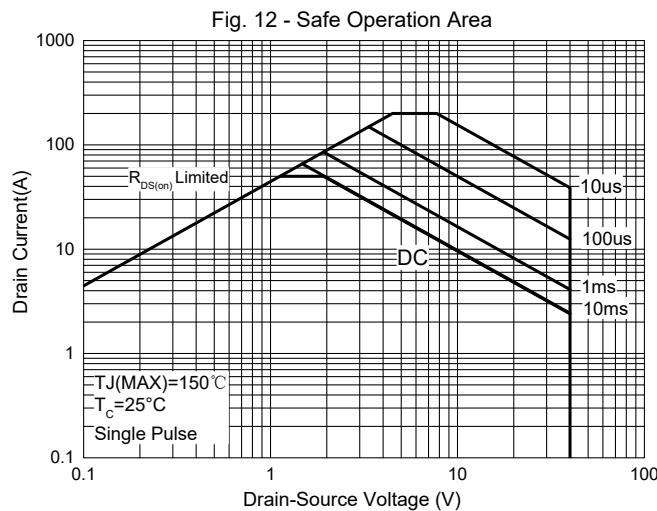
Fig. 6 - Gate Charge



Curve Characteristics



Curve Characteristics



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 5Kpcs/Reel

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